

# MBD1057-H20 Planar Tunnel Diode

## Technical Characteristics

### Product Features

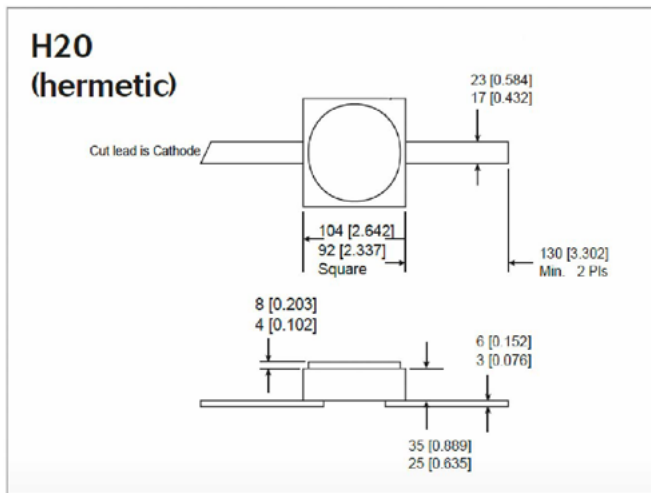
- Rugged Germanium Planar Construction
- Excellent Temperature Stability
- No DC Bias Required
- Wide Video Bandwidth
- MIL-STD-190500 & 883 Qualified

### Product Description

EclipseMDI MBD1057-H20, is a zero-bias, rugged Planar Tunnel Diode constructed with Germanium Planar. This tunnel diode exhibits excellent temperature stability, wide video bandwidth and is MIL-STD-190500 & MIL-STD-883C qualified. The MBD1057-H20 is also available in a non-hermetic (H20X) ceramic packages.

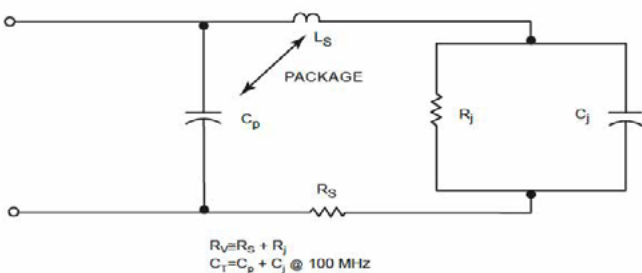
### Maximum Ratings

- Storage Temperature.....-65° to +125°C
- Operating Temperature.....-65° to +110°C
- Input Power Handling.....+17dBm CW or 3 ERG spike
- Soldering Temperature.....+160° C

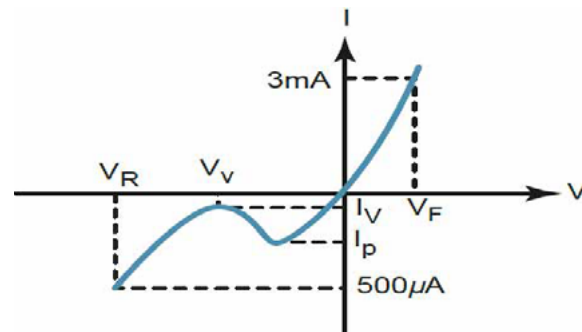


Parameters	Specifications				UNITS
	Conditions	MIN	Typical	MAX	
$I_p$		100		200	$\mu A$
$C_j$	$V_r = V_v$ $f = 100 \text{ MHz}$			.30	pF
$K[Y]$	$P_{in} = -20 \text{ dBm}$ $R_{Load} = 10 \text{ K}$ $f = 10 \text{ GHz}$		1000		mV/mW
$R_v$			180		$\Omega$ Ohms
$I_p/I_v$		2.5			
$V_r$	$I_f = 500 \mu A$		420		mV
$V_f$	$I_f = 3 \text{ mA}$			135	mV

### Diode equivalent circuit



### Back diode parameters



### About EclipseMDI

ECLIPSE Microdevices is located in San Jose, California. ECLIPSE has been developing high performance analog semiconductors for use in wireless radio frequency (RF), microwave, and millimeter wave for commercial and industrial applications. ECLIPSE has formed a strategic alliances - with foundries that features leading state-of-the-art process technologies and with manufacturing facilities for high-volume production of innovative RFICs.

### Product Export Classification

ECCN: EAR 99 (unless otherwise specified)  
 HTS: 8542330000